

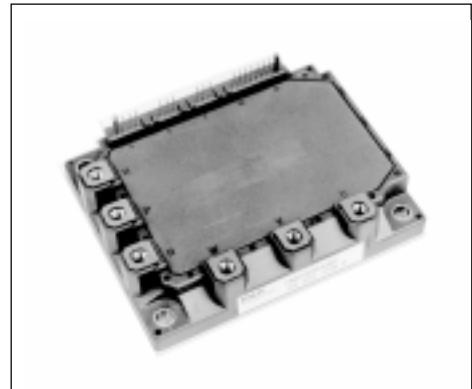
# 6MBP75RA120

## IGBT-IPM R series

1200V / 75A 6 in one-package

### ■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- Compatible with existing IPM-N series packages
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



### ■ Maximum ratings and characteristics

#### ● Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item	Symbol	Rating		Unit
		Min.	Max.	
DC bus voltage	V <sub>DC</sub>	0	900	V
DC bus voltage (surge)	V <sub>DC(surge)</sub>	0	1000	V
DC bus voltage (short operating)	V <sub>SC</sub>	200	800	V
Collector-Emitter voltage	V <sub>CES</sub>	0	1200	V
INV   Collector current	DC	I <sub>c</sub>	-	75 A
	1ms	I <sub>CP</sub>	-	150 A
	DC	-I <sub>c</sub>	-	75 A
Collector power dissipation	P <sub>c</sub>	-	500	W
Junction temperature	T <sub>j</sub>	-	150	°C
Input voltage of power supply for Pre-Driver	V <sub>CC</sub> *1	0	20	V
Input signal voltage	V <sub>in</sub> *2	0	V <sub>z</sub>	V
Input signal current	I <sub>in</sub>	-	1	mA
Alarm signal voltage	V <sub>ALM</sub> *3	0	V <sub>CC</sub>	V
Alarm signal current	I <sub>ALM</sub> *4	-	15	mA
Storage temperature	T <sub>STG</sub>	-40	125	°C
Operating case temperature	T <sub>Op</sub>	-20	100	°C
Isolating voltage (Case-Terminal)	V <sub>ISO</sub> *5	-	AC2.5	kV
Screw torque	Mounting (M5)	-	3.5 *6	N·m
	Terminal (M5)	-	3.5 *6	N·m

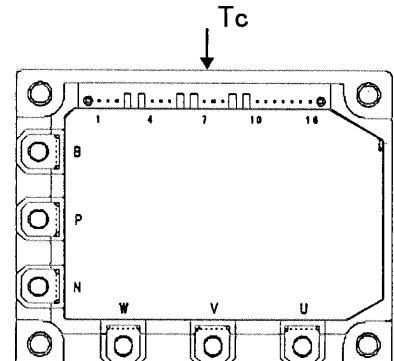


Fig.1 Measurement of case temperature

\*1 Apply V<sub>CC</sub> between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

\*2 Apply V<sub>in</sub> between terminal No. 2 and 1, 5 and 4, 8 and 7, 13,14,15 and 10.

\*3 Apply V<sub>ALM</sub> between terminal No. 16 and 10.

\*4 Apply I<sub>ALM</sub> to terminal No. 16.

\*5 50Hz/60Hz sine wave 1 minute.

\*6 Recommendable Value : 2.5 to 3.0 N·m

#### ● Electrical characteristics of power circuit (at Tc=Tj=25°C, V<sub>CC</sub>=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
INV	I <sub>CES</sub>	V <sub>CE</sub> =1200V input terminal open	-	-	1.0	mA
	V <sub>CES(sat)</sub>	I <sub>c</sub> =75A	-	-	2.6	V
	V <sub>F</sub>	-I <sub>c</sub> =75A	-	-	3.0	V

● Electrical characteristics of control circuit(at  $T_c=T_j=25^\circ\text{C}$ ,  $V_{cc}=15\text{V}$ )

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply current of P-line side Pre-driver(one unit)	$I_{ccp}$	$f_{sw}=0$ to 15kHz $T_c=-20$ to $100^\circ\text{C}$ *7	3	-	18	mA
Power supply current of N-line side three Pre-driver	$I_{ccn}$	$f_{sw}=0$ to 15kHz $T_c=-20$ to $100^\circ\text{C}$ *7	10	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON OFF	1.00 1.25	1.35 1.60	1.70 1.95	V
Input zener voltage	$V_z$	$R_{in}=20\text{k ohm}$	-	8.0	-	V
Over heating protection temperature level	$T_{COH}$	$V_{DC}=0\text{V}$ , $I_c=0\text{A}$ , Case temperature	110	-	125	°C
Hysteresis	$T_{CH}$		-	20	-	°C
IGBT chips over heating protection temperature level	$T_{JOH}$	surface of IGBT chips	150	-	-	°C
Hysteresis	$T_{JH}$		-	20	-	°C
Collector current protection level	INV	$I_{oc}$ $T_j=125^\circ\text{C}$	113	-	-	A
Over current protection delay time (Fig.2)	$t_{DOC}$	$T_j=25^\circ\text{C}$ Fig.2	-	10	-	μs
Under voltage protection level	$V_{UV}$		11.0	-	12.5	V
Hysteresis	$V_H$		0.2	-	-	V
Alarm signal hold time	$t_{ALM}$		1.5	2	-	ms
SC protection delay time	$t_{SC}$	$T_j=25^\circ\text{C}$ Fig.3	-	-	12	μs
Limiting resistor for alarm	$R_{ALM}$		1425	1500	1575	ohm

\*7 Switching frequency of IGBT

● Dynamic characteristics(at  $T_c=T_j=125^\circ\text{C}$ ,  $V_{cc}=15\text{V}$ )

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	$t_{on}$	$I_C=75\text{A}$ , $V_{DC}=600\text{V}$	0.3	-	-	μs
	$t_{off}$		-	-	3.6	μs
Switching time (FWD)	$t_{rr}$	$I_F=75\text{A}$ , $V_{DC}=600\text{V}$	-	-	0.4	μs

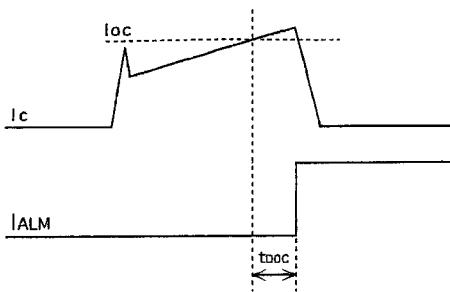


Fig.2 Definition of OC delay time

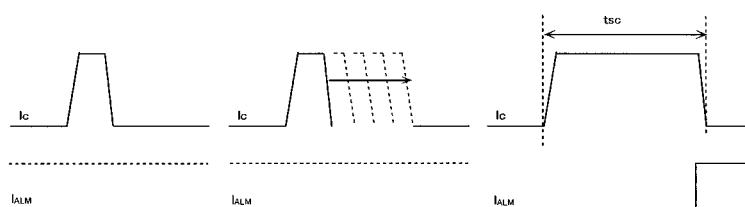


Fig.3 Definition of tsc

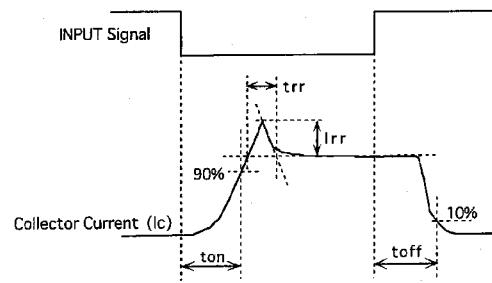


Fig.4 Definition of switching time

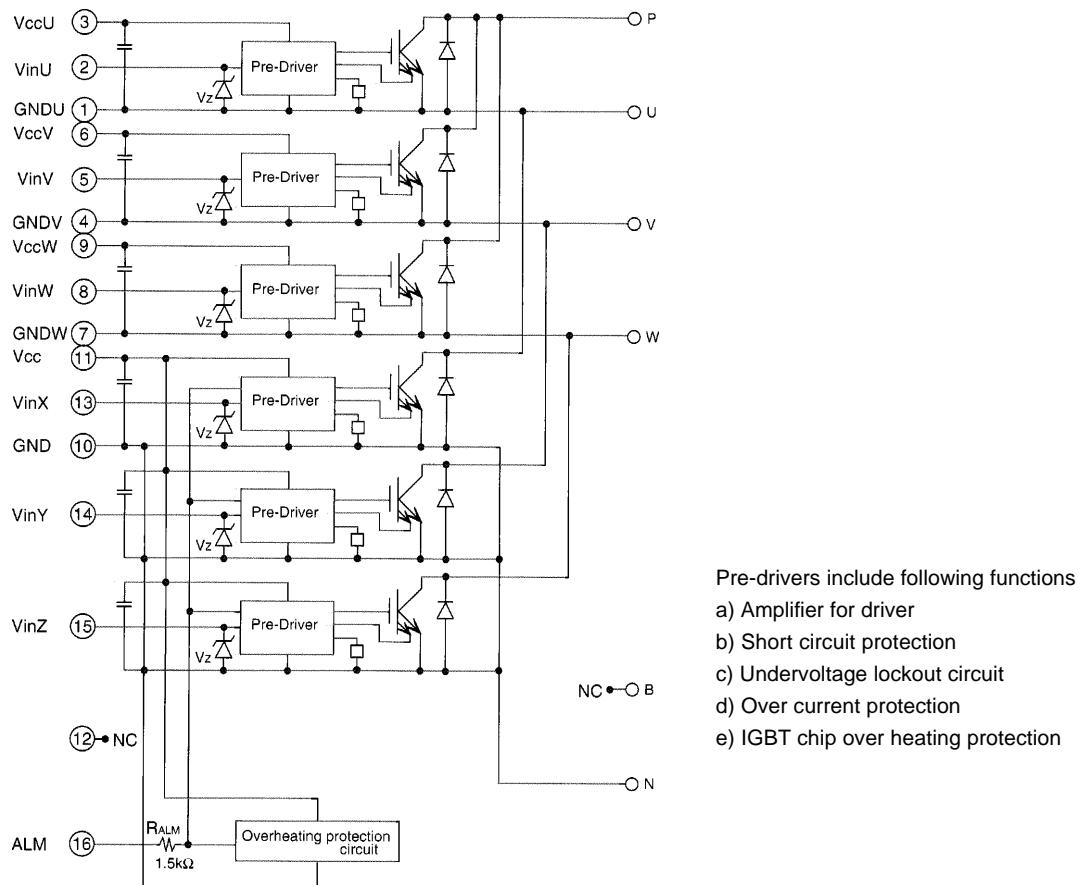
● Thermal characteristics( $T_c=25^\circ\text{C}$ )

Item		Symbol	Typ.	Max.	Unit
Junction to Case thermal resistance	INV	$R_{th(j-c)}$	-	0.25	°C/W
		$R_{th(j-c)}$	-	0.73	°C/W
Case to fin thermal resistance with compound		$R_{th(c-f)}$	0.05	-	°C/W

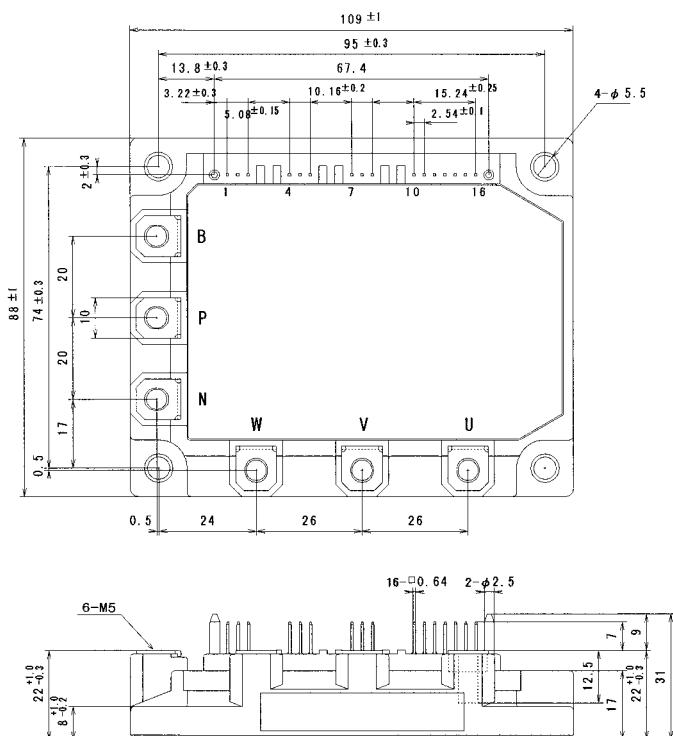
● Recommendable value

Item		Symbol	Min.	Typ.	Max.	Unit
DC bus voltage		$V_{DC}$	200	-	800	V
Operating power supply voltage range of Pre-driver		$V_{cc}$	13.5	15	16.5	V
Switching frequency of IPM		$f_{sw}$	1	-	20	kHz
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m
	Terminal (M5)	-	2.5	-	3.0	N·m

## ■ Block diagram



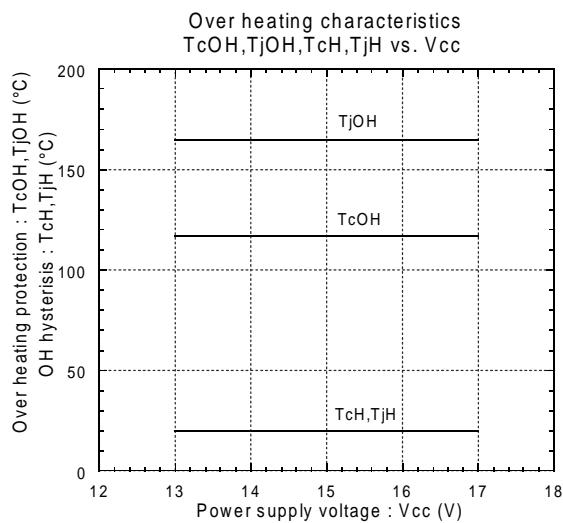
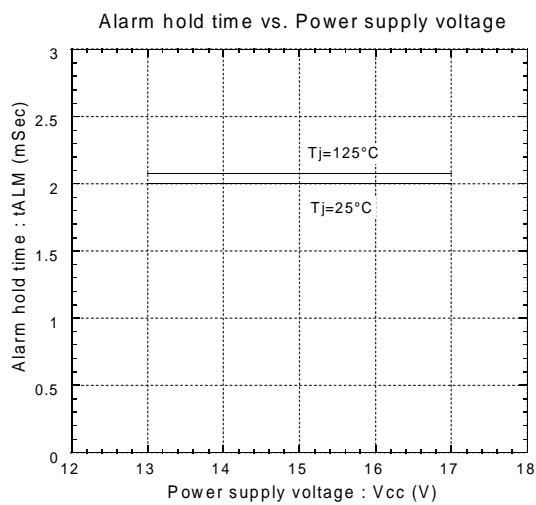
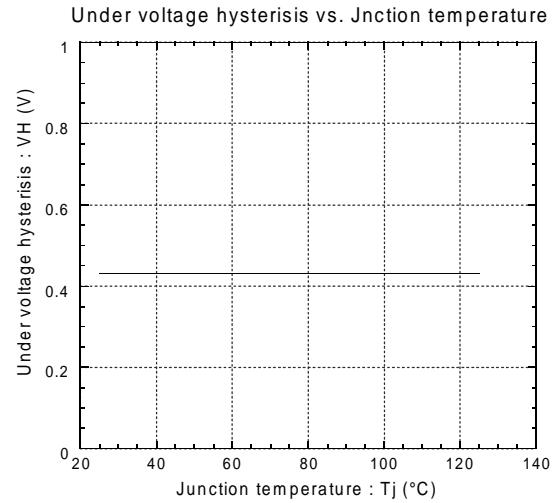
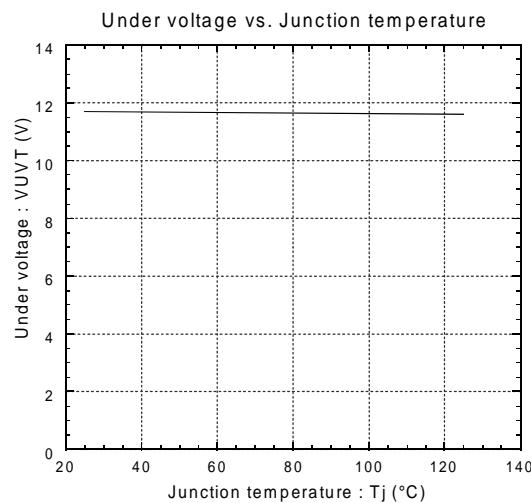
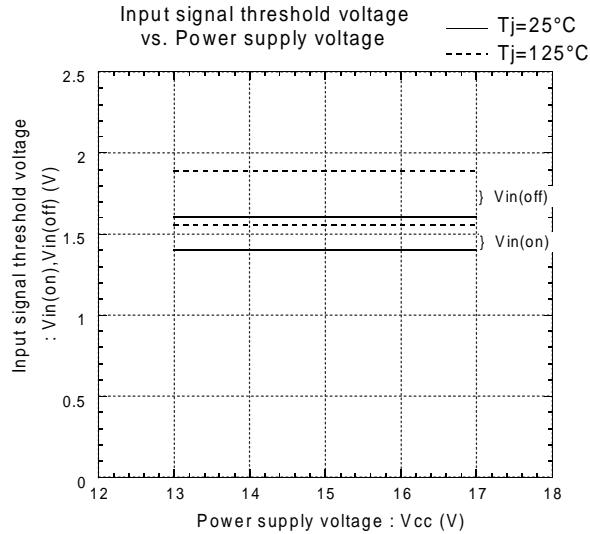
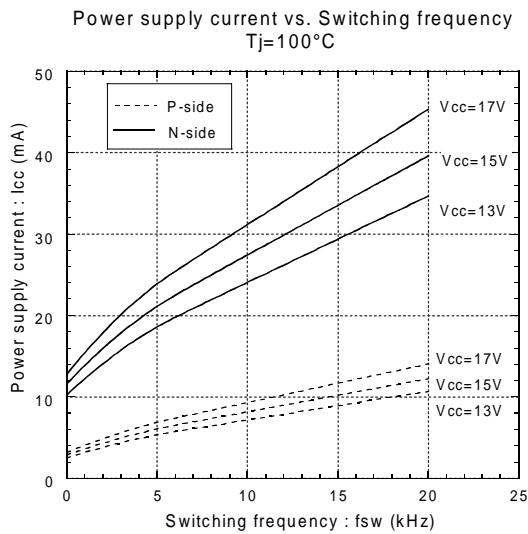
## ■ Outline drawings, mm



Mass : 440g

## ■ Characteristics (Representative)

### ● Control Circuit



## ● Inverter

